Xianhe Liu

List of Publications by Year in descending order

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759233 888059 24 541 12 17 citations h-index g-index papers 24 24 24 609 times ranked citing authors all docs docs citations

#	Article	IF	CITATIONS
1	Engineering the Carrier Dynamics of InGaN Nanowire White Light-Emitting Diodes by Distributed p-AlGaN Electron Blocking Layers. Scientific Reports, 2015, 5, 7744.	3.3	93
2	Controlled Coalescence of AlGaN Nanowire Arrays: An Architecture for Nearly Dislocationâ€Free Planar Ultraviolet Photonic Device Applications. Advanced Materials, 2016, 28, 8446-8454.	21.0	90
3	An electrically pumped surface-emitting semiconductor green laser. Science Advances, 2020, 6, eaav7523.	10.3	70
4	Scalable Nanowire Photonic Crystals: Molding the Light Emission of InGaN. Advanced Functional Materials, 2017, 27, 1702364.	14.9	48
5	Selective area epitaxy of AlGaN nanowire arrays across nearly the entire compositional range for deep ultraviolet photonics. Optics Express, 2017, 25, 30494.	3.4	42
6	N-polar InGaN nanowires: breaking the efficiency bottleneck of nano and micro LEDs. Photonics Research, 2022, 10, 587.	7.0	31
7	III-nitride nanostructures: Emerging applications for Micro-LEDs, ultraviolet photonics, quantum optoelectronics, and artificial photosynthesis. Progress in Quantum Electronics, 2022, 85, 100401.	7.0	26
8	Oxygen defect dominated photoluminescence emission of Sc <i>x</i> Allâ^' <i>x</i> N grown by molecular beam epitaxy. Applied Physics Letters, 2021, 118, .	3.3	22
9	Micrometer scale InGaN green light emitting diodes with ultra-stable operation. Applied Physics Letters, 2020, 117, .	3.3	21
10	Improving the Efficiency of Transverse Magnetic Polarized Emission from AlGaN Based LEDs by Using Nanowire Photonic Crystal. IEEE Photonics Journal, 2018, 10, 1-11.	2.0	20
11	Controlling Defect Formation of Nanoscale AlN: Toward Efficient Current Conduction of Ultrawidea∈Bandgap Semiconductors. Advanced Electronic Materials, 2020, 6, 2000337.	5.1	19
12	High efficiency InGaN nanowire tunnel junction green micro-LEDs. Applied Physics Letters, 2021, 119, .	3.3	16
13	Crystallographic Effects of GaN Nanostructures in Photoelectrochemical Reaction. Nano Letters, 2022, 22, 2236-2243.	9.1	12
14	Molecular beam epitaxial growth and characterization of AlN nanowall deep UV light emitting diodes. Applied Physics Letters, 2017, 111, 101103.	3.3	10
15	Emerging Applications of Illâ€Nitride Nanocrystals. Physica Status Solidi (A) Applications and Materials Science, 2020, 217, 1900885.	1.8	8
16	Monolithic integration of multicolor InGaN LEDs with uniform luminescence emission. Optics Express, 2021, 29, 32826.	3.4	7
17	Nanoscale and quantum engineering of III-nitride heterostructures for high efficiency UV-C and far UV-C optoelectronics. Japanese Journal of Applied Physics, 2021, 60, 110501.	1.5	3
18	AlGaN nanowire deep ultraviolet optoelectronics. , 2017, , .		2

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#	Article	IF	CITATIONS
19	Ultra-High-Q Microring Resonators using Single Crystal Aluminum Nitride on Sapphire Platform. , 2019, , .		1
20	AlGaN nanowire deep ultraviolet light emitting diodes and lasers. , 2017, , .		O
21	AlGaN Nanowire Photonic Crystals: Design, Epitaxy, and High Efficiency Deep UV LEDs. , 2018, , .		O
22	Realization of High-Q Microring Resonators with Single Crystal Aluminum Nitride. , 2019, , .		O
23	AlGaN Nanocrystal Ultraviolet LEDs and Laser Diodes. , 2019, , .		O
24	III-Nitride Nanocrystals: From Low Threshold Ultraviolet Laser Diodes to High Efficiency Artificial Photosynthesis. , 2019, , .		0